TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74LVX4051F, TC74LVX4051FT, TC74LVX4051FK TC74LVX4052F, TC74LVX4052FT, TC74LVX4052FK TC74LVX4053F, TC74LVX4053FT, TC74LVX4053FK

#### TC74LVX4051F/FT/FK

8-Channel Analog Multiplexer/Demultiplexer TC74LVX4052F/FT/FK Dual 4-Channel Analog Multiplexer/Demultiplexer

#### TC74LVX4053F/FT/FK

Triple 2-Channel Analog Multiplexer/Demultiplexer

The TC74LVX4051/4052/4053 are high-speed, low-voltage drive analog multiplexer/demultiplexers using silicon gate CMOS technology. In 3 V and 5 V systems these can achieve high-speed operation with the low power dissipation that is a feature of CMOS.

The TC74LVX4051/4052/4053 offer analog/digital signal selection as well as mixed signals. The 4051 has an 8-channel configuration, the 4052 has an 4-channel × 2 configuration, and the 4053 has a 2-channel × 3 configuration.

The switches for each channel are turned ON by the control pin digital signals.

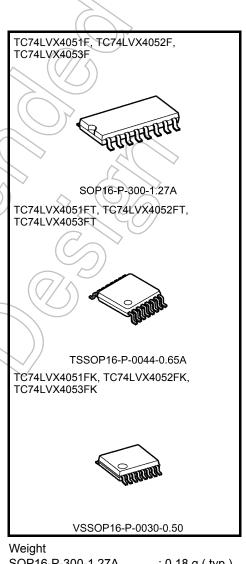
Although the control signal logical amplitude ( $V_{CC}$  – GND) is small, the device can perform large-amplitude ( $V_{CC}$  –  $V_{EE}$ ) signal switching.

For example, if  $V_{CC} = 3 \text{ V}$ , GND = 0 V, and  $V_{EE} = -3 \text{ V}$ , signals between -3 V and +3 V can be switched from the logical circuit using a single 3 V power supply.

All control input pins are equipped with a newly developed input protection circuit that avoids the need for a diode on the plus side (forward side from the input to the V<sub>CC</sub>). As a result, for example, 5 V signals can be permitted on the inputs even when the power supply voltage to the circuits is off. As a result of this input power protection, the TC74LVX4051/4052/4053 can be used in a variety of applications, including in the system which has two power supplies, and in battery backup circuits.

# Features

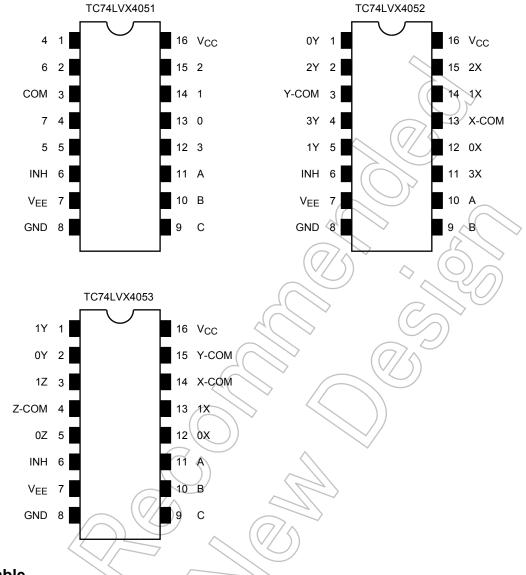
- Low ON resistance:  $R_{on} = 22 \Omega$  (typ.) (V<sub>CC</sub> V<sub>EE</sub> = 3 V)  $R_{on} = 15 \Omega$  (typ.) (V<sub>CC</sub> - V<sub>EE</sub> = 6 V)
- High speed:  $t_{pd} = 3 \text{ ns} (typ.) (V_{CC} = 3.0 \text{ V})$
- Low power dissipation:  $I_{CC} = 4 \mu A (max) (Ta = 25^{\circ}C)$
- Input level: V<sub>IL</sub> = 0.8 V (max) (V<sub>CC</sub> = 3 V) V<sub>IH</sub> = 2.0 V (min) (V<sub>CC</sub> = 3 V)
- Power down protection is provided on all control inputs
- Pin and function compatible with 74HC4051/4052/4053



	Veight
: 0.18 g ( typ	SOP16-P-300-1.27A
65A : 0.06 g ( typ	SSOP16-P-0044-0.65A
50 : 0.02 g ( typ	/SSOP16-P-0030-0.50
65A : 0.06 g ( typ	SSOP16-P-0044-0.65A

Start of commercial production 2000-09

# Pin Assignment (top view)



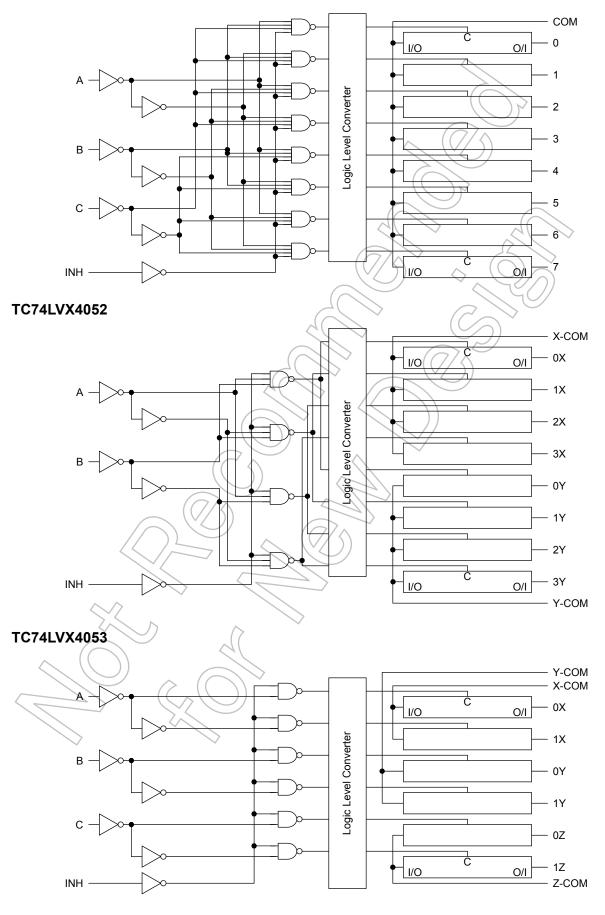
# **Truth Table**

	Control	I Inputs			"ON" Channel	
Inhibit	C*	В	A	TC74LVX4051	TC74LVX4052	TC74LVX4053
L		L V	L	0	0X, 0Y	0X, 0Y, 0Z
			Н	1	1X, 1Y	1X, 0Y, 0Z
	)	Н	)) L	2	2X, 2Y	0X, 1Y, 0Z
1	L	) F	Н	3	3X, 3Y	1X, 1Y, 0Z
L	Н		L	4		0X, 0Y, 1Z
L	Н	L	Н	5		1X, 0Y, 1Z
L	Н	Н	L	6		0X, 1Y, 1Z
L	Н	Н	Н	7		1X, 1Y, 1Z
Н	Х	Х	Х	None	None	None

X: Don't care, \*: Except TC74LVX4052

# System Diagram

#### TC74LVX4051



#### Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V <sub>CC</sub>	–0.5 to 7.0	v	
Fower supply voltage	$V_{CC}$ to $V_{EE}$	-0.5 to 7.0		
Control input voltage	V <sub>IN</sub>	-0.5 to 7.0	V	$\langle \rangle$
Switch I/O voltage	V <sub>I/O</sub>	$V_{EE}$ – 0.5 to $V_{CC}$ + 0.5	V	<u> </u>
Input diode current	I <sub>IK</sub>	-20	mA	
I/O diode current	I <sub>IOK</sub>	±20	mA	$\overline{\overline{\overline{n}}}$
Switch through current	lΤ	±25	mA	$\bigvee \bigcirc$
DC $V_{CC}$ or ground current	ICC	±50	mA	$\sim$
Power dissipation	PD	180	mW	7(
Storage temperature	T <sub>stg</sub>	-65 to 150	<b>0</b> °C	

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
	V <sub>CC</sub>	2 to 6	
Power supply voltage	VEE	-4 to 0	V
	V <sub>CC</sub> to V <sub>EE</sub>	2 to 6	
Input voltage	VIR	0 to 6.0	V
Switch I/O voltage	V <sub>1/O</sub>	V <sub>EE</sub> to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	_40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 (V_{CC} = 3.3 $\pm$ 0.3 V)	ns/V
Input rise and fait linte	avav	0 to 20 (V <sub>CC</sub> = 5 $\pm$ 0.5 V)	115/ V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.



#### **Electrical Characteristics**

## **DC Electrical Characteristics**

Character	Characteristics		istics Symbol Test Condition			٦	Га = 25°С	)	Ta = -40	to 85°C	Unit												
Character	151105	Symbol	Test Condition	$V_{EE}(V)$	$V_{CC}(V)$	Min	Тур.	Max	Min	Max	Unit												
					2.0	1.5	_	X	1.5	_													
	High-level	VIH			3.0	2.0	_	À	2.0	_													
	i ligii-level	VН			4.5	3.15	_	Å	3.15	_													
Input voltage					6.0	4.2	-((	77~	4.2	—	V												
input voltage					2.0	_<	) - (	0.5	—	0.5	v												
	Low-level	VIL			3.0	(		0.8	—	0.8													
	Low-Icvel	۷IL			4.5		$\bigcirc$	1.35	—	1.35													
					6.0	$\mathcal{A}$		1.8	f	1.8													
			$V_{IN} = V_{IL} \text{ or } V_{IH}$	GND	2.0	Ĥ	200		24	$\geq$													
			$V_{I/O} = V_{CC}$ to $V_{EE}$	GND	3.0	2/~	45	86	5	108													
		$R_{ON}$ II/O = 2 mA		GND	4.5		24 <	37	SH	46													
ON resistance			R <sub>ON</sub>	R <sub>ON</sub>	R <sub>ON</sub>	RON	RoN		1//0 2 11// (	-3.0	3.0	_	17	26	L FC	33	Ω						
						$V_{IN} = V_{IL} \text{ or } V_{IH}$	GND	2.0	× —	28	73	<u>~</u>	84	25									
			$V_{I/O} = V_{CC} \text{ or } V_{EE}$	GND	3.0		22	38	—	44													
															$I_{I/O} = 2 \text{ mA}$	GND	4.5	—	(17/	27	—	31	
			40	-3.0	3.0		15	24	—	28													
			$V_{IN} = V_{IL} \text{ or } V_{IH}$	GND	2.0	_	10	25		35													
Difference of ON resistance between	ce between $\Delta R_{ON} V_{I/C}$		$V_{I/O} = V_{CC}$ to $V_{EE}$	GND	3.0	$\searrow$	5	15	—	20	Ω												
switches		$I_{I/O} = 2 \text{ mA}$	GND	4.5	_	5	13	—	18														
				-3.0	3.0	_	5	10	—	15													
Input/Output lea	kage		$V_{OS} = V_{CC}$ or GND	GND	3.0	<u> </u>	—	±0.25	—	±2.5													
current (switch OFF)		IOFF	V <sub>IS</sub> = GND to V <sub>CC</sub> V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub>	-3.0	3.0	_	—	±0.5	—	±5.0	μA												
Input/Output lea	ikage		$V_{OS} = V_{CC} \text{ or } GND$	GND	3.0	_	_	±0.25	_	±2.5	•												
current (switch ON, out	out open)	Vin	$V_{IN} = V_{IL} \text{ or } V_{IH}$	-3.0	3.0			±0.5	_	±5.0	μA												
Control input cu	rrent	IIN	$V_{IN} = V_{CC} \text{ or } GND$	GND	6.0	_		±0.1	_	±0.1	μA												
Quippont auro		N-	Mar Nor of CND	GND	3.0	_	—	4.0	_	40.0	^												
Quiescent supp	ly current	lcc	$V_{IN} = V_{CC}$ or GND	-3.0	3.0	—	—	8.0	—	80.0	μA												

# AC Electrical Characteristics ( $C_L = 50 \text{ pF}$ , Input: $t_r = t_f = 3 \text{ ns}$ , GND = 0 V)

Characteristics	Currente e l	Та	at Canadition			7	Га = 25°С	)	Ta = -40	to 85°C	Unit											
Characteristics Symbol		Test Condition		$V_{\text{EE}}(V)$	$V_{CC}(V)$	Min	Тур.	Max	Min	Max	Unit											
Phase difference between				GND	2.0	—	3.2	6.0	—	6.9												
	φl/O	Alltime		GND	3.0		1.8	3.0		3.5	ns											
input and output	φι/Ο	All type	:5	GND	4.5	_	1.3	1.8		2.1	115											
				-3.0	3.0	_	1.1	1.3	$\leq$	1.5												
				GND	2.0	_	9.0	TT.	2_	20												
Output enable time	t <sub>pZL</sub>	Figure	1 (Note 1)	GND	3.0	$\leq$	5.7	9.0	_	11	ns											
	t <sub>pZH</sub>	rigure		GND	4.5		4.5	6.0		7.0	115											
				-3.0	3.0	_((	5.8	8.0		10												
				GND	2.0		13.5	21		25												
Output disable time	t <sub>pLZ</sub>	Figure	1 (Note 1)	GND	3.0 🗸	1(	11.3	15	AF	18	ns											
	tpHZ		rigure	ligure i (inote i)	GND	4.5	$\mathbb{R}$	10.3	12	$\geq$	14	115										
																	-3.0	3.0	$\langle \gamma \rangle$	10.9	13	
Control input capacitance	C <sub>in</sub>	All type	es (Note 2)	— (	$\sim$	2	5	(10)	C4)/	10	pF											
		4051		G	$\bigcirc$		11	25		25												
COMMON terminal capacitance	CIS	C <sub>IS</sub>	C <sub>IS</sub>	C <sub>IS</sub>	C <sub>IS</sub>	C <sub>IS</sub>	C <sub>IS</sub>	C <sub>IS</sub>	4052	Figure 2 (Note 2)	-3.0	3.0	—	9(	20	—	20	pF				
		4053	. ,		$\langle \rangle$		$\overline{\overline{z}}$	15		15												
		4051	- C	$\left( \right)$			6	) 13		13												
SWITCH terminal capacitance	C <sub>OS</sub>	4052	Figure 2 (Note 2)	-3.0	3.0	$\sim$	6	13	—	13	pF											
		4053		$\langle \rangle$			) )6	13		13												
		4051					3	6		6												
Feedthrough capacitance	C <sub>IOS</sub> 4052 Fig	4052 Figure 2 (Note 2)	C <sub>IOS</sub> 4052 Figure	Figure 2 (Note 2)	-3.0	3.0	_~	3	6		6	pF										
		4053					3	6		6												
		4051		$\sim$		$\geq$	14															
Power dissipation capacitance	CPD	CPD 4052 Figure 2		GND	6.0	—	24	—	—	—	pF											
		4053			$\left( \right)$		18															

Note 1:  $R_L = 1 k\Omega$ 

Note 2: Cin, CIS, COS and CIOS are guaranteed by the design.

Note 3: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance of IC which is calculated from the operating current consumption without load.

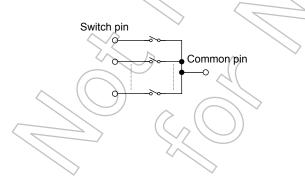
Average operating current can be obtained by the equation:

ICC (opr) = CPD · VCC · fIN + ICC

# Analog Switch Characteristics (GND = 0 V, $Ta = 25^{\circ}C$ ) (Note)

Characteristics	Symbol	Test Condition					Test Condition			Тур.	Unit
Characteristics	Symbol	Test Condition		V <sub>EE</sub> (V)	$V_{CC}(V)$	тур.	Unit				
			$V_{IN} = 2.0 V_{p-p}$	0	3.0	0.100					
Sine Wave Distortion (T.H.D)		R <sub>L</sub> = 10 kΩ, C <sub>L</sub> = 50 pF, f <sub>IN</sub> = 1 kHz	$V_{IN} = 4.0 \ V_{p\text{-}p}$	Q	4.5	0.030	%				
		$V_{IN}=6.0 \ V_{p\text{-}p}$	-0.3	3.0	0.020						
			4051		$\sum$	150					
			4052	0	3.0	180					
		Adjust $f_{IN}$ voltage to obtain 0dBm at $V_{OS}$ .	4053	$(// \uparrow$		200					
_		Increase f <sub>IN</sub> frequency until dB	4051			150					
Frequency response (switch ON)	f <sub>max</sub>	meter reads –3dB.	4052	0	4.5	180	MHz				
		$R_L = 50 \Omega$ , $C_L = 10 pF$ , $f_{IN} = 1 MHz$ , sine wave	4053	ک		200					
	Figure 3	Figure 3	4051		$\mathcal{A}($	150					
			4052	-3.0	3.0	180					
		(	4053	$\Diamond$	(O)	200					
		$V_{IN}$ is centered at $(V_{CC} - V_{EE})/2$ .	0	3.0	/_45						
		Adjust input for 0dBm. $R_L = 600 \Omega$ , $C_L = 50 pF$ , $f_{IN} = 1 MI$	0	4.5	-45						
Feed through attenuation (switch OFF)	_	Figure 4	, ,	-3.0	3.0	-45	dB				
(Switch OFF)			(	0	3.0	-60					
		$R_L = 50 \ \Omega$ , $C_L = 10 \ pF$ , $f_{IN} = 1 \ MH$	0	0 4.5	-60						
			-3.0	3.0	-60						
Crosstalk		$R_L$ = 600 $\Omega,C_L$ = 50 pF, f <sub>IN</sub> = 1 MI	Hz, square wave	0	3.0	90					
(control input to signal output)	—	$(t_r = t_f = 6 \text{ ns})$		0	4.5	150	mV				
		Figure 5		-3.0	3.0	120					
Oracastalla		Adjust V <sub>IN</sub> to obtain 0dBm at input		0	3.0	-45					
Crosstalk (between any switches)		$R_L = 600 \ \Omega$ , $C_L = 50 \ pF$ , $f_{IN} = 1 \ MI$	0	4.5	-45	dB					
	$\bigcirc$ )`	Figure 6		-3.0	3.0	-45					

Note: These characteristics are determined by design of devices.



# AC Test Circuit

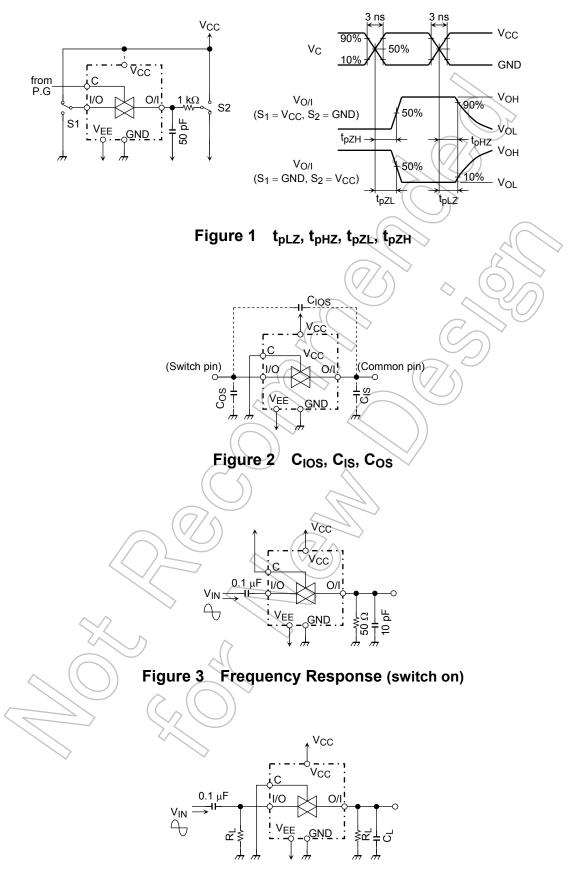
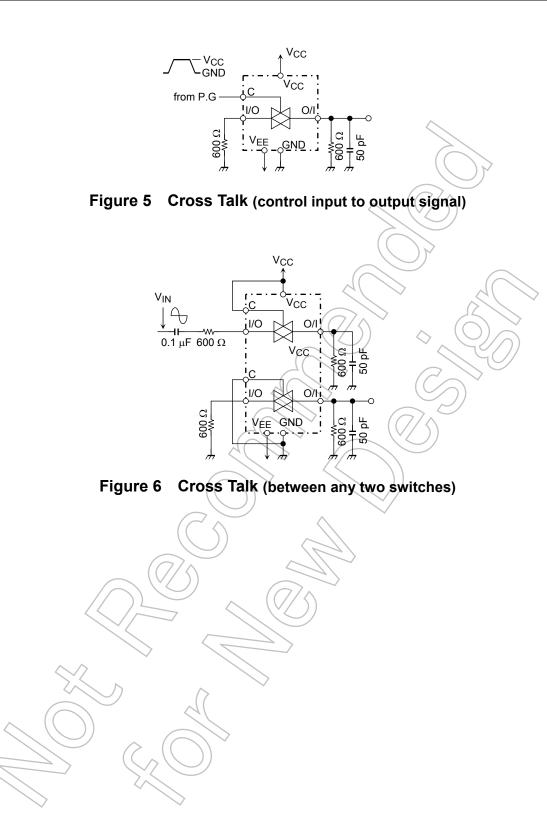


Figure 4 Feedthrough

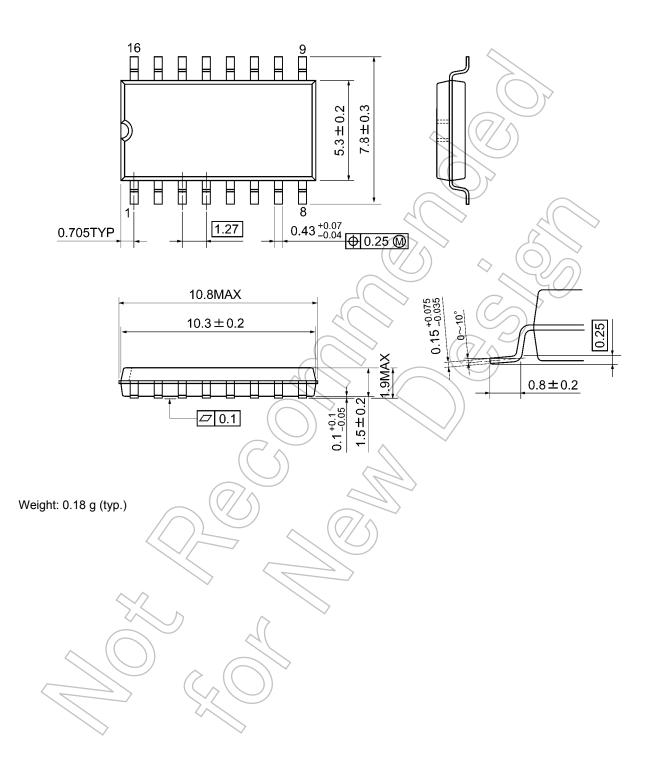




## **Package Dimensions**

SOP16-P-300-1.27A

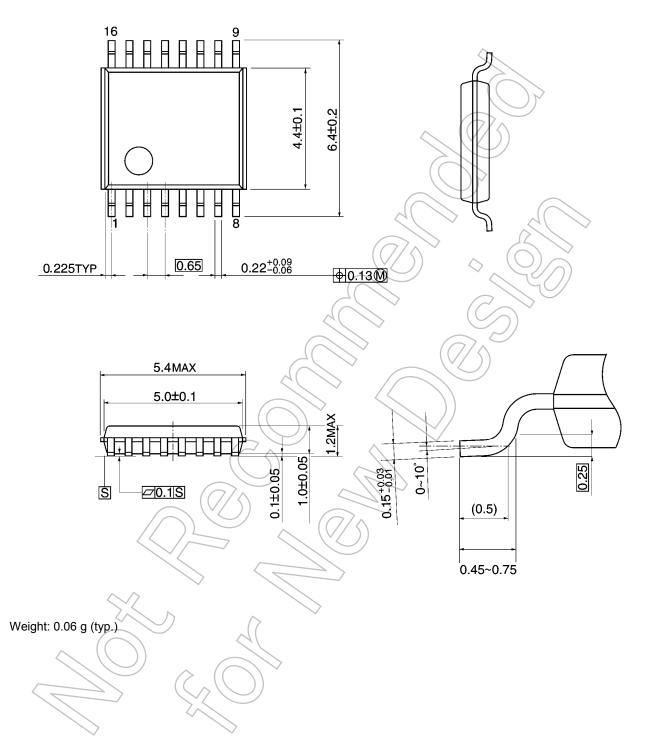
Unit: mm



# Package Dimensions

TSSOP16-P-0044-0.65A

Unit: mm

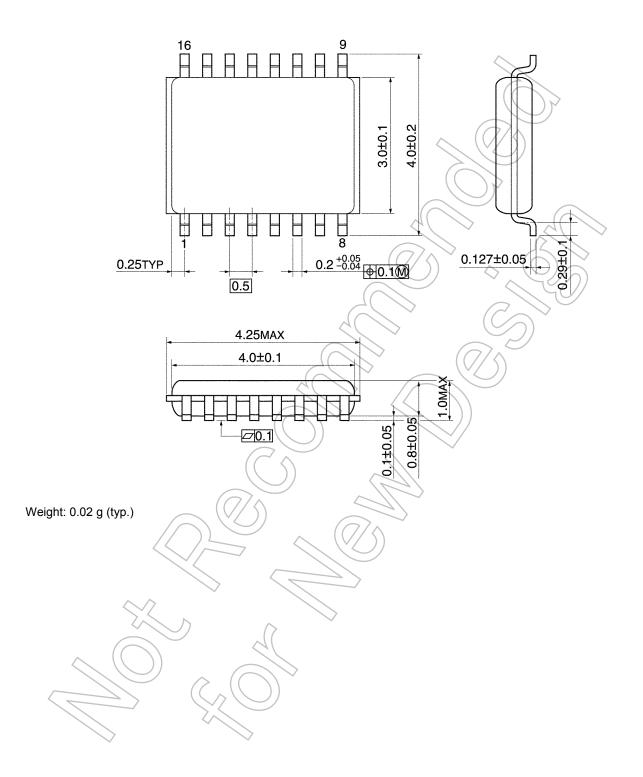


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## **Package Dimensions**

VSSOP16-P-0030-0.50

Unit: mm



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